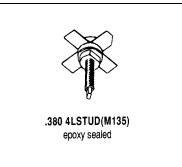


140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013 PHONE: (215) 631-9840 FAX: (215) 631-9855

### **RF & MICROWAVE TRANSISTORS FM MOBILE APPLICATIONS**

### Features

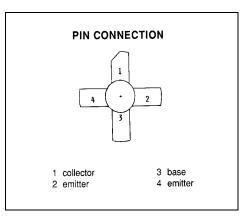
- 175MHz
- 12.5 VOLTS
- GOLD METALIZATION
- Pout = 20WATTS
- Gp = 8.0 dB MINIMUM
- COMMON EMITTER CONFIGURATION



**MS1406** 

### DESCRIPTION:

The MS1406 is a silicon NPN transistor designed for 12.5V AM Class C amplifiers operating in the 118–136 MHz aviation band and for 28V FM Class C amplifiers used in ground station transmitters. Diffused emitter ballast and gold metalization provide maximum ruggedness and reliability.



## ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector- Base Voltage	65	V
V <sub>CEO</sub>	Collector-Emitter Voltage	35	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
Ι <sub>c</sub>	Continuous Collector Current	3.0	Α
PD	Total Dissipation	30	W
Tj	Junction Temperature	200	º C
T <sub>STG</sub>	Storage Temperature	-65 to +200	<sup>⁰</sup> C

### Thermal Data

R <sub>TH(J-C)</sub>	Thermal Resistance Junction-case	5.8	°C/W		

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# MS1406

# ELECTRICAL SPECIFICATIONS (Tcase = $25^{\circ}$ C)

### STATIC

Symbol	Test Conditions		Value			
Symbol	Symbol Test Conditions		Min.	Typ.	Max.	Unit
BV <sub>CES</sub>	l <sub>c</sub> = 200 mA	V <sub>BE</sub> = 0 mA	65			V
BV <sub>CEO</sub>	I <sub>c</sub> = 200 mA	I <sub>B</sub> = 0 mA	35			V
BV <sub>EBO</sub>	I <sub>E</sub> = 10 mA	$I_c = 0 mA$	4.0			V
I <sub>CBO</sub>	V <sub>CB</sub> = 30 V	I <sub>E</sub> = 0 mA			1.0	mA
h <sub>FE</sub>	V <sub>CE</sub> = 5 V	I <sub>c</sub> = 200 mA	10		200	

### DYNAMIC

Symbol	Test Conditions			Value			
Symbol			Min.	Typ.	Max.	Unit	
POUT	f = 175MHz	<b>P</b> <sub>IN</sub> = <b>3.0W</b>	$V_{CE} = 28V$	20			w
GP	f = 175MHz	$\mathbf{P}_{IN} = \mathbf{3.0W}$	$V_{CE} = 28V$	8.2			dB
η <sub>c</sub>	f = 175MHz	$\mathbf{P}_{IN} = \mathbf{3.0W}$	$V_{CE} = 28V$	60			%
Сов	V <sub>CB</sub> = 30V	f = 1 MHz				35	pf

### **IMPEDANCE DATA**

FREQ	$Z_{IN}(\Omega)$	$Z_{CL}(\Omega)$
175 MHz	1.1 + j1.15	9.0 - j9.60

P<sub>IN</sub> = 3.0W

 $V_{CC}=28V$ 



## **MS1406**

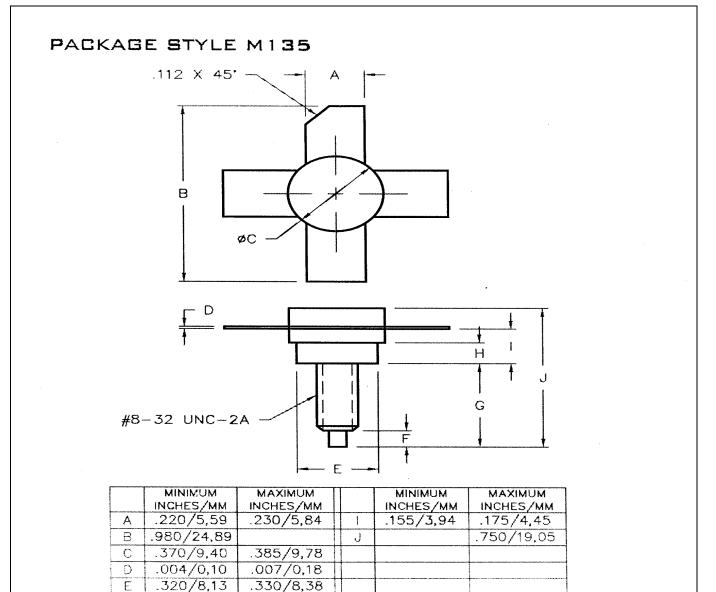
### PACKAGE MECHANICAL DATA

F

G H .100/2,54

.450/11,43

.090/2,29



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.130/3,30

.490/12,45

.100/2.54